

General Description

The SE8803 is a regulator with very low dropout and dual-output. It specifically designed for today's electricity meter applications.

The SE8803 has two voltage inputs and two voltage outputs. Output1 has two distinct requirements for the power supplies for the electricity meters. The first requirement is low power consumption. The second is low noise. Output1 uses a very unique design to achieve very low power consumption while providing a very low noise power output for electricity meter applications.

The second output is capable of delivering 150mA output current at a very low dropout voltage of 0.82V (Typical). The high precision output at 2% ensures that the accurate power supply requirement is met with enough margins in many tough applications.

Both of Outputs also provides Over Current Protection (OCP) and Over Temperature Protection (OTP), these features will ensure a safe operating environment for electricity meter applications.

The SE8803 is available in SOP and PSOP8 package.

Features

Output 1

- Output voltage of 5.0V (Typ.)
- Low quiescent Current
- Over-current/Over-temperature Protection.
- Minimum external components.
- Output voltage tolerances of ±2%
- ESD rating is 2KV (Per MIL-STD-883D)

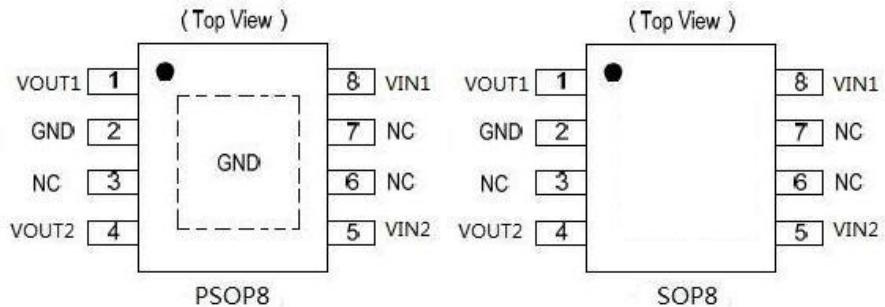
Output 2

- Output voltage of 11.6V (Typ.)
- Output current up to 150mA (Typ.)
- Current limiting Over thermal Protection.
- Minimum external components.
- Output voltage tolerances of ±2%
- Input Voltage up to 30V
- Operating Junction Temperature Range -40 to +125°C
- ESD rating is 2KV (Per MIL-STD-883D)

Applications

- Electricity meter.
- Networking Equipments where low noise and low power consumption is required.

Pin Configuration



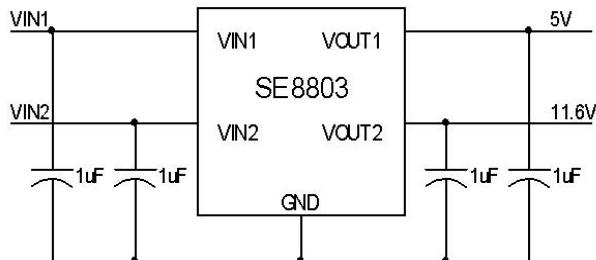


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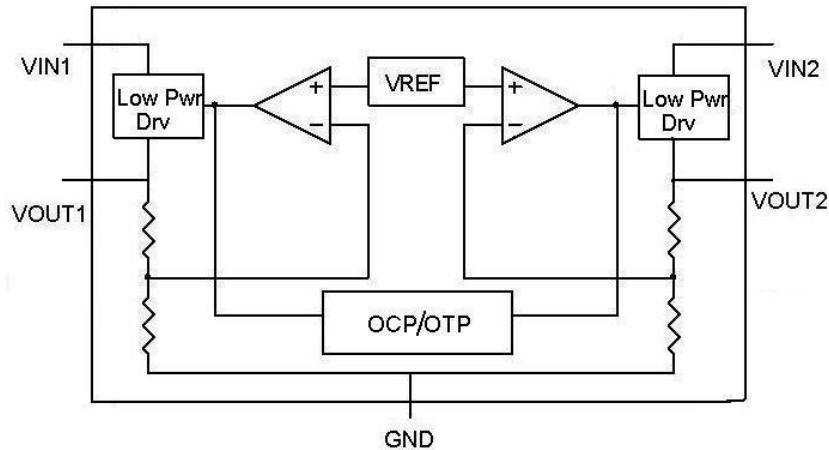
SE8803

Dual-Output Low Quiescent Current LDO

Typical Application



Functional Block Diagram



Ordering Information

Part Number	Marking Information	Package	Remarks
SE8803P	SE8803 YYWW-LF	PSOP8	YYWW means Production batch; LF: Lead Free
SE8803F		SOP8	

Absolute Maximum Rating

Parameter	Symbol	Maximum	Units
Power dissipation@25°C			
SOP8	P _D	0.9	W
PSOP8		1.1	
Input Voltage	V _{IN1}	-0.3~28	V
	V _{IN2}	-0.3~30	V
Operating Junction Temperature Range	T _J	-40 to +125	°C
Thermal Resistance			
SOP8	θ _{JA}	75	°C/W
PSOP8		65	
Lead Temperature (Soldering) 10 seconds	T _{LEAD}	260±5	°C
Storage Temperature	T _{STG}	-65 to +150	°C
ESD (HBM) Susceptibility	V _{ESD}	2	KV



Recommended Operating Conditions

Parameter	Symbol	Value	Units
Supply Input Voltage	V _{IN1}	7.0 to +22	V
	V _{IN2}	13 to +28	V
Junction Temperature	T _J	-40 to +85	°C

Electrical Characteristics

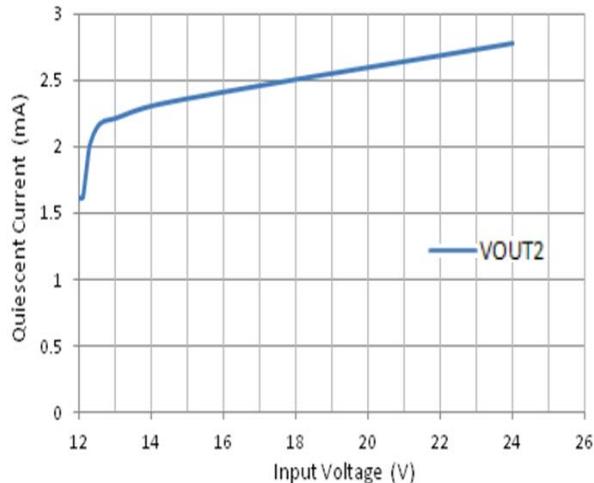
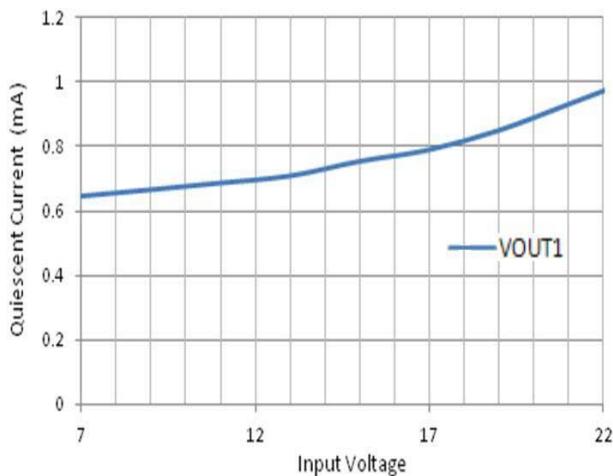
V_{IN1} = 8V, V_{IN2} = 13V; I_{OUT} = 10mA; C_{IN1} = C_{OUT1} = 1μF; C_{IN2} = C_{OUT2} = 1μF; T_J = 25°C; unless otherwise specified

Symbol	Parameter	Conditions	SE8803			Unit
			Min	Typ	Max	
V _{O1}	Output Voltage	I _{OUT} = 10mA	4.9	5	5.1	V
V _{O2}		I _{OUT} = 10mA	11.368	11.6	11.832	V
ΔV _{O1}	Line Regulation	7V ≤ V _{IN1} ≤ 20V	--	0.07	--	%/V
ΔV _{O2}		13V ≤ V _{IN2} ≤ 26V	--	0.11	--	%/V
ΔV _{O1}	Load Regulation	1mA ≤ I _{O1} ≤ 50mA	--	50	--	mV
ΔV _{O2}		10mA ≤ I _{O2} ≤ 150mA	--	320	--	mV
I _{Q1}	Quiescent Current	I _{O1} =10mA	--	0.65	--	mA
I _{Q2}		I _{O2} =10mA		2.21		mA
		I _{O2} =100mA		1.7		mA
ΔI _{Q1}	Quiescent Current Change	7V ≤ V _{IN} ≤ 20V	--	0.32	--	mA
I _{Q2}		13V ≤ V _{IN} ≤ 24V	--	0.56	--	mA
V _{D1}	Dropout Voltage	ΔV _{O1} =-2%	-	0.82	--	V
V _{D2}		ΔV _{O2} =-2%	-	0.82	--	V
I _{PK1}	Peak Output Current	V _{IN1} =8V	50	60	--	mA
		V _{IN1} =15V	90	100	--	mA
I _{PK2}		V _{IN2} = 13V	150	200	--	mA
ΔV _{O1} /ΔT	Average Output Voltage Tempco	I _{O1} = 10mA	--	0.1	--	mV/°C
ΔV _{O2} /ΔT		I _{O2} = 10mA	--	0.8	--	mV/°C
T _{OTP}	Thermal Protection Temperature		--	150	--	°C
V _{IN1} (Min)	Minimum Value of Input Voltage Required to Maintain Line Regulation	I _{O1} = 10mA	5.8	6.2	--	V
V _{IN2} (Min)		I _{O2} = 10mA	--	13	--	V

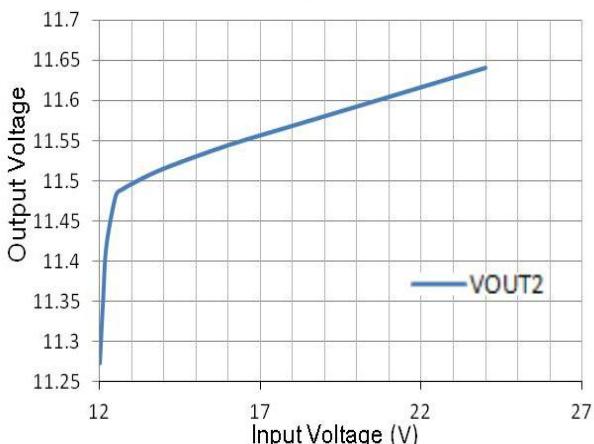
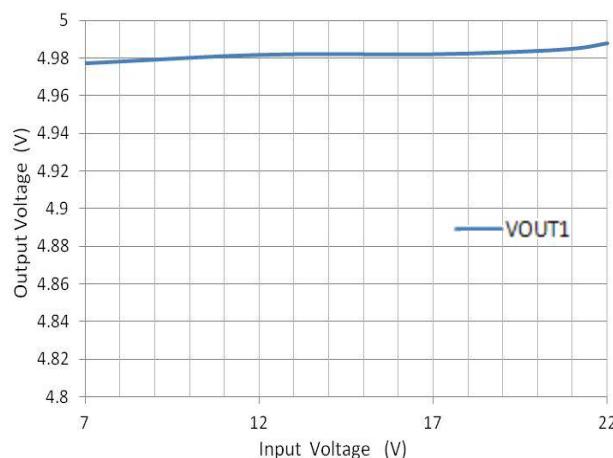


Typical Performance Characteristic

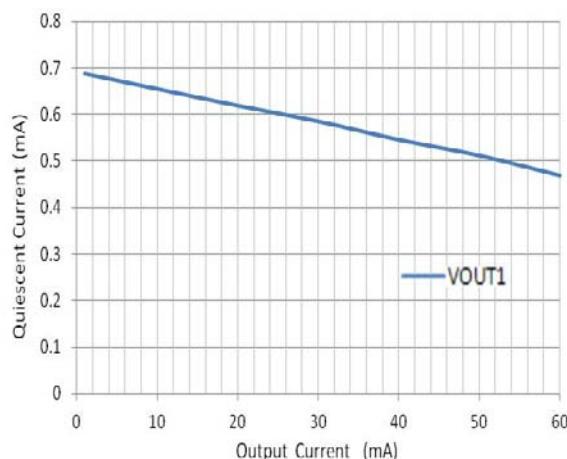
$V_{IN1} = 8V$, $V_{IN2} = 13V$, $I_{O1} = I_{O2} = 10mA$, $C_{IN} = C_{OUT} = 1\mu F$, $T_J = 25^{\circ}C$, unless specified otherwise.



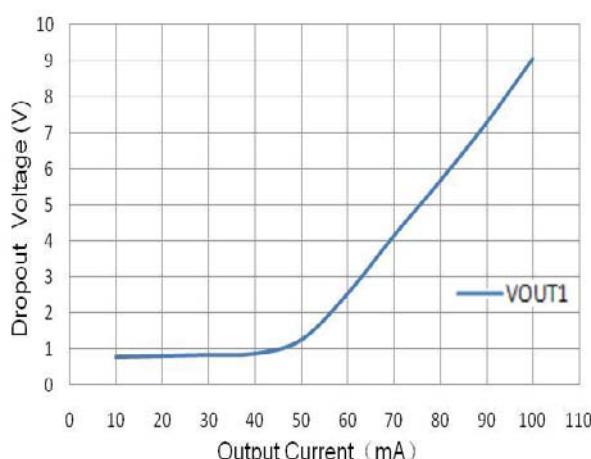
Quiescent Current VS Input Voltage



Output Voltage VS Input Voltage



Quiescent Current VS Output Current



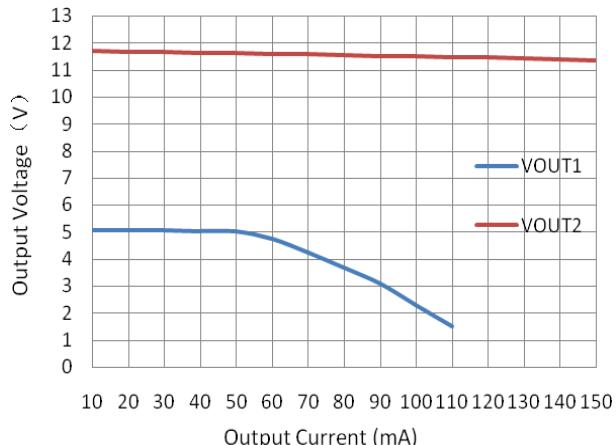
Dropout Voltage VS Output Current



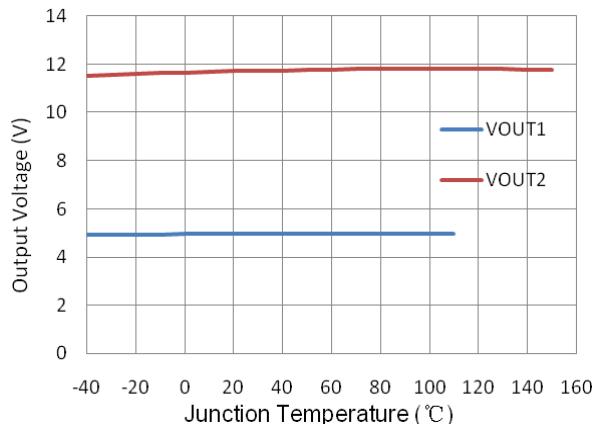
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Output Voltage VS Output Current



Output Voltage VS Junction Temperature

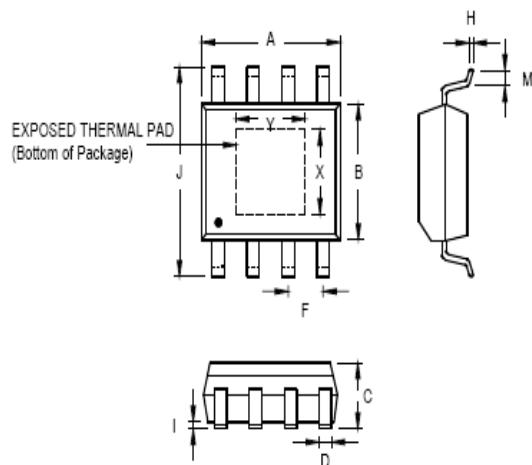


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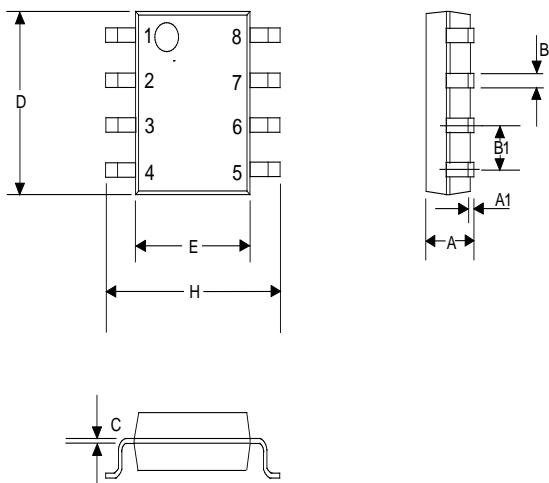
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Outline Drawing PSOP8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.801	5.004	0.189	0.197
B	3.810	3.988	0.150	0.157
C	1.346	1.753	0.053	0.069
D	0.330	0.508	0.013	0.020
F	1.194	1.346	0.047	0.053
H	0.191	0.254	0.008	0.010
I	0.000	0.152	0.000	0.006
J	5.791	6.198	0.228	0.244
M	0.406	1.270	0.016	0.050
X	2.057	2.515	0.081	0.099
Y	2.057	3.404	0.081	0.134

Outline Drawing SOP8



DIMENSIONS				
DIM ^N	INCHES		MM	
	MIN	MAX	MIN	MAX
A	0.0532	0.0688	1.35	1.75
A1	0.0040	0.0098	0.10	0.25
B	0.0130	0.0200	0.33	0.51
B1	0.050 BSC		1.27 BSC	
C	0.0075	0.0098	0.19	0.25
D	0.1890	0.1968	4.80	5.00
H	0.2284	0.2440	5.80	6.20
E	0.1497	0.1574	3.80	4.00

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